Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	401	349/43 and pad and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
L2	155	349/152 and pad and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
L3	96	349/143 and pad and expos\$4 and mask\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
L4		349/150 and pad and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
L5	80	349/152 and pad and expos\$4 and mask\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
S48	927	349/149	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:31
S49	963	349/187	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 15:29
S50	27	cutting-off adj plate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 15:37

S51	4883	expos\$4 near10 pad near10 etch\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 15:38
S52	237	(expos\$4 near10 pad near10 etch\$4) and gate and data and semiconductor and pixel and mask\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:15

S53	239	("1954691"	"2851408"	"2867541"	US-PGPUB;	OR	OFF	2005/05/19 16:28
		"2959483"	"3070441"	"3108904"	USPAT;			
		"3259782"	"3314871"	"3360450"	USOCR			
		"3525679"	"3554889"	"3665241"				
		"3675063"	"3755704"	"3789471"	İ			
		"3808048"	"3812559"	"3855499"				
		"3898146"	"3947716"	"3970887"				
				•				
		"3998678"	"4008412"	"4075535"				
		"4084942"	"4139773"	"4141405"				
		"4143292"	"4164680"	"4168213"				
		"4178531"	"4307507"	"4350926"				
		"4482447"	"4498952"	"4507562"				
		"4512912"	"4513308"	"4540983"				
		"4542038"	"4578614"	"4588921"				
		"4594527"	"4633131"	"4647400"		•		
		"4663559"	"4684353"	"4684540"				
		"4685996"	"4687825"	"4687938"				
		"4710765"	"4721885"	"4728851"				
		"4758449"	"4763187"	"4780684"				
		"4788472"	"4816717"	"4818914"				
		"4822466"	"4827177"	"4835438"				
		·						
		"4851254"	"4855636"	"4857161"				
		"4857799"	"4874981"	"4882659"				
		"4889690"	"4892757"	"4899081"				
		"4900584"	"4908539"	"4923421"				
		" <del>4</del> 926056"	"4933108"	"4940916"				
		"4943343"	"4956202"	"4956574"				
		"4964946"	"4987007"	"4990416"				
		"4990766"	"4994205"	"5007873"				
		"5015912"	"5019003"	"5036247"				
		"5038070"	"5043715"	"5054046"				·
		"5054047"	"5055077"	"5055744"	'			
		"5057047"	"5063323"	"5063327"				•
		"5064396"	"5066883"	"5075591"				
		"5075595"	"5075596"	"5079476"				
		"5085958"	"5089292"	"5089742"				
		"5089812"		•				,
								,
		1	"5101288"     "5117267"	"51031 <del>44</del>     "5117299"				•
		"5103145"						
		"5119386"						
		"5124558"		"5129850"				
			"5132676")					
		•	•	"5140219"	I			
		P .	"5141460"					
			"5142390"	•				
	1	"5148078"	"5148461"	"5150011"				
	1	"5150192"	"5151061"	"5153753"		1		
		"5153901"	"5155420"	"5156770"			İ	
		"5157304"		"5162704"				
		"5166456"		•		1		
1		"5173697"		•				
	1	"5185178"				1		
	1	"5191217"	•			]		
		"5199917"	"5192218"					
	1	"5202571"	"5203731"					
			•	•				
		"5204581"	"5205770"	"5209687"     "5313436"		1		
		"5210430"		"5212426"     "5214247"				
Search I	lictory 12/1	"5213712" 5/05-1:34:05.0	"5214346"   Backs 3	"5214347"     "5227622"				
C-/ Docu	ments and Se	5/0524:24:05: F	B	"5227699"    S.C.workspace	s\10713198[cuttin	g off plate	dry etchin	al.wsp
C. \DOCU	iniciio anu se		Posuments E		5\10/10100[Cuttill	p.acc		JF
I	1	"5229682"	l "5231606"	"5232549"	I	I	1	

S54	24	(expos\$4 near10 pad near10 (dry adj etch\$4)) and gate and data and semiconductor and pixel and mask\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 16:29
S55	94	(expos\$4 near10 pad near10 etch\$4) and gate and data and semiconductor and pixel and mask\$4 and cut\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/20 11:08
S56	2.	(expos\$4 near10 pad near10 etch\$4) and gate and data and semiconductor and pixel and mask\$4 and cut\$4-off	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/20 11:08
S57	998	349/143	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:24
S58	367	349/150	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:24
S59	1653	349/43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2005/05/21 10:25
S60	357	349/43 and pad and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
S61	73	349/150 and pad and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33

S62	131	349/152 and pad and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
S63	114	349/143 and pad and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:37
S65	84	349/143 and pad and expos\$4 and mask\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
S67	66	349/152 and pad and expos\$4 and mask\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
S69	291	349/43 and pad and expos\$4 and mask\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:39
S70	111	(expos\$4 near10 pad near10 etch\$4) and gate and data and semiconductor and pixel and mask\$4 and ((mask cutting-off) near10 metal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:08
S71	9	(expos\$4 near10 pad near10 etch\$4) and gate and data and semiconductor and pixel and mask\$4 and ((mask cutting-off) near10 metal) and ((three "3") adj mask\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:54
S72	1857216	(dry adj etch\$4) nea10 insulat\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:11

S73	4990943	S72 (liquid adh crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:10
S74	2348219	S72 (liquid adh crystal) and expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:10
S75	150088	(dry adj etch\$4) nea10 insulat\$4 near10 expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:15
S76	11537	S75 and (liquid adj crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:12
S77	2992	(S75 near10 remov\$4)and (liquid adj crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:13
S78	833	(S75 near10 remov\$4)and (liquid adj crystal) and pad	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:13
S79	228	(S75 near10 remov\$4)and (liquid adj crystal) and (gate adj pad) and (data adj pad)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:14
S80	1281	(dry adj etch\$4) near10 insulat\$4 near10 expos\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:15

S81	40	(dry adj etch\$4) near10 insulat\$4 near10 expos\$4 and (gate adj pad) and (data adj pad)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:16
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